

Technical Data Data Sheet N0270, Rev. - Green Products

MUR540AX

MUR540AX ULTRAFAST PLASTIC RECTIFIER

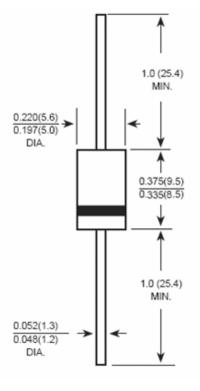
Applications:

- Switching Power Supply
- Power Switching Circuits
- General Purpose

Features:

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop, High Efficiency
- Low Power Loss
- Super Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In Inches / mm



DO-201AD

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Marking Diagram:



Where XXXXX is YYWWL

| MUR | = Device Type |
|-----|--------------------------|
| 5 | = Forward Current (5A) |
| 40 | = Reverse Voltage (400V) |
| AX | = Configuration |
| SSG | = SSG |
| ΥY | = Year |
| WW | = Week |
| L | = Lot Number |
| | |

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

| Device | Package | Shipping |
|----------|-----------------------|----------------|
| MUR540AX | DO-201AD (Pb-Free) | 1250pcs / tape |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|---|--------------------|---|------|-------|
| Peak Inverse Voltage | V _{RWM} | - | 400 | V |
| Average Forward Current | I _{F(AV)} | 50% duty cycle @TC =105℃ rectangular wave form | 5.0 | A |
| Peak One Cycle Non- Repetitive Surge Current | I _{FSM} | 8.3ms, Half Sine pulse | 80 | A |



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Electrical Characteristics:

| Characteristics | Symbol | Condition | Max. | Units |
|-----------------------|-----------------|---|------|-------|
| Forward Voltage Drop | VF | @ I _F = 5A, Pulse, T _J = 25℃ | 1.25 | V |
| Reverse Current | I _{R1} | @V _R = rated VR T _J = 25℃ | 10 | μA |
| | I _{R2} | @V _R = rated VR T _J = 125℃ | 500 | μA |
| Reverse Recovery Time | t _{rr} | I _F =500mA, I _R =1A,and I _{rm} =250mA | 50 | ns |

* Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|--|------------------|-----------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +150 | °C |
| Storage Temperature | T _{stg} | - | -55 to +150 | °C |
| Maximum Thermal Resistance Junction to Case | R _{θJC} | - | 3.5 | °C /W |
| Approximate Weight | wt | - | 1.02 | g |
| Case Style | | DO-201AD | | |



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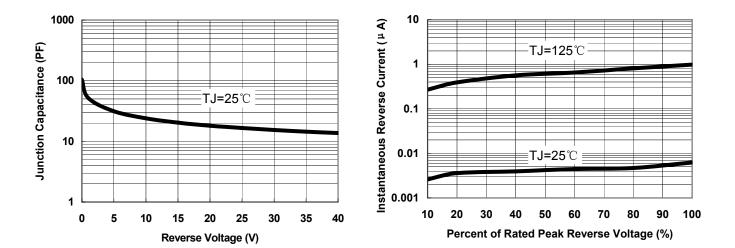




Fig.2-Typical Reverse Characteristics

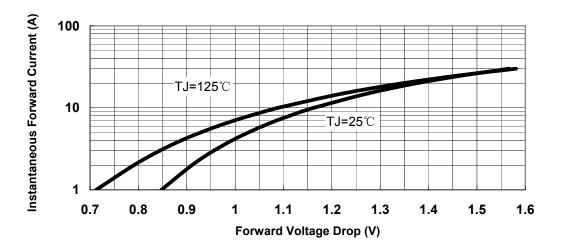


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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